## NSN 5962-00-271-1610

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View Online at https://aerobasegroup.com/nsn/5962-00-271-1610 **Body Length:** Between 0.240 inches and 0.275 inches **Body Width:** Between 0.240 inches and 0.260 inches **Body Height:** Between 0.030 inches and 0.070 inches **Maximum Power Dissipation Rating:** 450.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and programmable and programmed and w/storage **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Current-mode logic **Input Circuit Pattern:** 8 input **Case Outline Source And Designator:** T0-86 joint electron device engineering council **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 50.0 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 82679-nw180 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 flat leads Shelf Life: N/a **Unit Of Measure:** 

Demilitarization: Yes - demil/mli

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